

RP131x SERIES

LOW ON RESISTANCE / LOW VOLTAGE 1A LDO

NO.EA-174-230801

OUTLINE

The RP131x Series are voltage-regulators with a built-in low ON-resistance transistor and output current is 1A capability. These ICs are capable of the low input voltage (Min.1.6V) and also the minimum output voltage can be set from 0.8V. (The output voltage is fixed in the IC.)

Each of these ICs consists of a voltage reference unit, an error amplifier, a resistor net for setting output voltage, a chip enable circuit, current limit circuits for over-current and short, and a thermal-shutdown circuit.

A standby mode with ultra low supply current can be realized with the chip enable function.

The packages for these ICs are DFN1616-6B and DFN(PL)1820-6 which are suitable for high density mounting of the ICs on boards. SOT-89-5, HSOP-6J and TO-252-5-P2 with high power dissipation are also available.

FEATURES

Output Current	Min. 1A
Supply Current	Typ. 65μA
Standby Current	Typ. 0.15μA
Input Voltage Range	1.6V to 6.5V
Output Voltage Range	0.8V to 5.5V ⁽¹⁾ (0.1V steps)
Dropout Voltage	Typ. 0.5V (Vоит=2.8V, Iоит=1A)
Ripple Rejection	Typ. 70dB (f=1kHz, Vоит=2.8V)
Output Voltage Accuracy	±1.0%
• Temperature-Drift Coefficient of Output Voltage	Typ. ±100ppm/°C
Line Regulation	Typ. 0.05%/V
Load Regulation	Typ. 20mV at Iоυт=300mA, Typ. 80mV at Iоυт=1A
Packages	DFN1616-6B, DFN(PL)1820-6, SOT-89-5, HSOP-6J,
	TO-252-5-P2
Built-in Inrush current limit circuit	Typ. 500mA
Built-in Fold-Back Protection Circuit	Typ. 250mA (Current at short mode)
Built-in Thermal Shutdown Circuit	Thermal Shutdown Temperature ; Typ. 165°C
	Released Temperature ; Typ. 135°C
Built-in Auto Discharge Function	D version
• Ceramic capacitors are recommended to be used wi	th this IC 2.2μF or more (Vo∪τ≤3.6V)
	$4.7\mu F$ or more (Vout>3.6V)

APPLICATIONS

- Power source for battery-powered equipment.
- Power source for portable communication equipment.
- Power source for electrical appliances such as cameras, VCRs and camcorders.
- · Power source for Notebook PC.
- Power source for home appliances.

(1) For other voltages, please refer to MARK INFORMATIONS.

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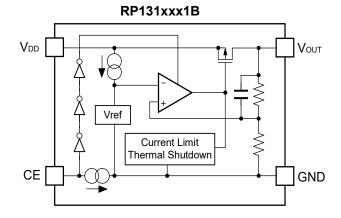
SELECTION GUIDE

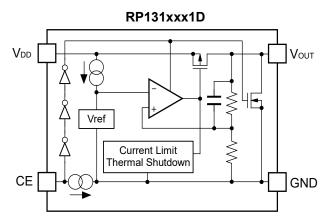
The output voltage, auto discharge function, package for the ICs can be selected at the user's request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
RP131Lxx1*-TR	DFN1616-6B	5,000 pcs	Yes	Yes
RP131Kxx1*-TR DFN(PL)1820-6		5,000 pcs	Yes	Yes
RP131Hxx1*-T1-FE	SOT-89-5	1,000 pcs	Yes	Yes
RP131Sxx1*-E2-FE	HSOP-6J	1,000 pcs	Yes	Yes
RP131Jxx1*-T1-FE	TO-252-5-P2	3,000 pcs	Yes	Yes

- xx : The output voltage can be designated in the range from 0.8V(08) to 5.5V(55) in 0.1V steps. (For other voltages, please refer to MARK INFORMATIONS.)
 - *: The auto discharge function at off state are options as follows.(1)
 - (B) without auto discharge function at off state
 - (D) with auto discharge function at off state

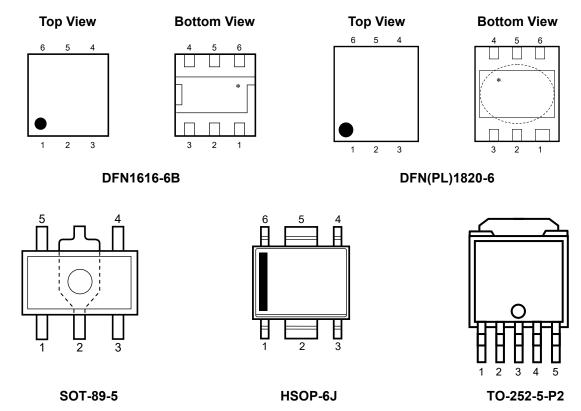
BLOCK DIAGRAMS





⁽¹⁾ Auto-discharge function quickly lowers the output voltage to 0V, when the chip enable signal is switched from the active mode to the standby mode, by releasing the electrical charge accumulated in the external capacitor.

PIN DESCRIPTIONS



^{*}Tab is GND level. (They are connected to the reverse side of this IC.) The tab is better to be connected to the GND, but leaving it open is also acceptable.

RP131L (DFN1616-6B) Pin Description

Pin No.	Symbol	Pin Description
1	VOUT	Output Pin ⁽¹⁾
2	VOUt	Output Pin ⁽¹⁾
3	GND	Ground Pin
4	CE	Chip Enable Pin ("H" Active)
5	VDD	Input Pin ⁽¹⁾
6	VDD	Input Pin ⁽¹⁾

⁽¹⁾ When you use this IC, please make sure be wired with 1pin with 2pin and 5pin with 6pin.

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RP131K (DFN(PL)1820-6) Pin Description

Pin No.	Symbol	Pin Description
1	VOUT	Output Pin ⁽¹⁾
2	VOUT	Output Pin ⁽¹⁾
3	GND	Ground Pin
4	CE	Chip Enable Pin ("H" Active)
5	VDD	Input Pin ⁽¹⁾
6	VDD	Input Pin ⁽¹⁾

RP131H (SOT-89-5) Pin Description

Pin No.	Symbol	Pin Description
1	NC	No Connection
2	GND	Ground Pin
3	CE	Chip Enable Pin ("H" Active)
4	VDD	Input Pin
5	VOUT	Output Pin

RP131S (HSOP-6J) Pin Description

Pin No.	Symbol	Pin Description
1	VOUT	Output Pin
2	GND	Ground Pin ⁽²⁾
3	NC	No Connection
4	CE	Chip Enable Pin ("H" Active)
5	GND	Ground Pin ⁽²⁾
6	VDD	Input Pin

RP131J (TO-252-5-P2) Pin Description

Pin No.	Symbol	Pin Description
1	Vоит	Output Pin
2	GND	Ground Pin ⁽³⁾
3	GND	Ground Pin ⁽³⁾
4	CE	Chip Enable Pin ("H" Active)
5	V _{DD}	Input Pin

⁽¹⁾ When you use this IC, please make sure be wired with 1pin with 2pin and 5pin with 6pin.

⁽²⁾ When you use this IC, please make sure be wired with 2pin and 5pin.

⁽³⁾ When you use this IC, please make sure be wired with 2pin and 3pin.

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ABSOLUTE MAXIMUM RATINGS

Symbol		Item	Rating	Unit	
VIN	Input Voltage	7.0	V		
Vce	Input Voltage (CE Pin)	Input Voltage (CE Pin)			
Vоит	Output Voltage	-0.3 to V _{IN} +0.3	V		
	Power Dissipation ⁽¹⁾	DFN1616-6B, JEDEC STD.51-7	2400		
		DFN(PL)1820-6, JEDEC STD.51-7	2200	mW	
P_D		SOT-89-5, JEDEC STD.51-7	2600		
		HSOP-6J, JEDEC STD.51-7	2700		
		TO-252-5-P2, JEDEC STD.51-7	3800		
Tj	Junction Temperature	-40 to 125	°C		
Tstg	Storage Temperature	-55 to 125	°C		

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field.

The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS

Symbol	Item	Rating	Unit
V _{IN}	Input Voltage	1.6 to 6.5	V
Ta	Operating Temperature Range	-40 to 85	°C

RECOMMENDED OPERATING CONDITIONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such ratings by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

⁽¹⁾ Refer to POWER DISSIPATION for detailed information.

R	P ₁	131	v
•			

ELECTRICAL CHARACTERISTICS

VIN=Set Vout+1V, Iout=	1mA									
The specification in [is	checked	and	guaranteed	by	design	engineering	at	-40°C≤Ta≤85°C,	unless
otherwise noted.										

RP131xxx1B/D $(Ta = 25^{\circ}C)$

Symbol	Item	Condition	Min.	Тур.	Max.	Unit	
		T- 25°C	Vоит>1.5V	×0.99		×1.01	V
\ /	O to t. \ / = t = =	Ta = 25°C	Vouт≤1.5V	-15		15	mV
Vout	Output Voltage	_40°C ≤ Ta t≤ 85°C	Vоит>1.5V	×0.974		×1.018	V
		-40°C ≤ 1at≤ 65°C	Vо∪т≤1.5V	-40		27	mV
ΔV_{OUT}	Load Regulation	0.1mA ≤ Iouт ≤ 300mA			20	40	mV
$\Delta {\sf I}$ оит	Load Regulation	0.1mA ≤ I _{ОUT} ≤ 1A			80	120	IIIV
VDIF	Dropout Voltage		Refer to the follow	ving table	9		
Iss	Supply Current	Iоит=0mA (VIN=6.5V)			65	90	μА
Istandby	Standby Current	VCE=0V, VIN=6.5V			0.15	0.60	μА
$\Delta V_{ ext{OUT}}/$	Line Regulation	Set V _{OUT} +0.5V ≤ V _{IN} ≤ *However, V _{IN} ≥ 1.6V	6.5V		0.05	0.1	%/V
RR	Ripple Rejection	f=1kHz Ripple 0.2Vp-p lout=100mA	Vо∪т≤3.3V		70		dB
KK			V _{OUT} >3.3V		60		uБ
Vin	Input Voltage			1.6		6.5	V
Ішм	Output Current Limit			1			Α
Δ V ουτ/ Δ T a	Output Voltage Temperature Coefficient	–40°C≤Ta≤85°C			±100		ppm /°C
Isc	Short Current Limit	V _{OUT} =0V			250		mA
I PD	CE Pull-down Current				0.3		μА
VCEH	CE Input Voltage "H"			1.0			V
Vcel	CE Input Voltage "L"					0.4	V
en	Output Noise	BW=10Hz to 100kHz,	Іоит=1mA		45		μVrms
TTSD	Thermal Shutdown Temperature	Junction Temperature			165		°C
Trsr	Thermal Shutdown Released Temperature	Junction Temperature		135		°C	
RLow	Low Output Nch Tr. ON Resistance (of D version)	V _{IN} =4.0V, V _{CE} =0V			30		Ω

All test items listed under Electrical Characteristics are done under the pulse load condition (Tj≈Ta = 25°C) except for Output Noise, Ripple Rejection, Output Voltage Temperature Coefficient, Dropout Voltage at 1A Output Current and Thermal Shutdown items.

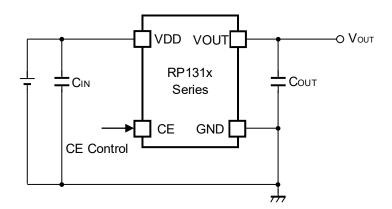
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	04	2	4 v
$\mathbf{\Gamma}$	ГІ	J	IX

The specification in \square is checked and guaranteed by design engineering at -40° C \leq Ta \leq 85°C, unless otherwise noted.

Dropout Voltage						(Ta = 25°C)
Output Voltage	Dropout Voltage VDIF (V)					
V оит (V)	Condition	Тур.	Max.	Condition	Тур.	Max.
0.8 ≤ V _{OUT} < 0.9		0.600	0.780		1.100	1.650
0.9 ≤ V _{OUT} < 1.0		0.550	0.690		1.050	1.500
1.0 ≤ Vouт < 1.1		0.450	0.610		1.000	1.450
1.1 ≤ Vouт < 1.2	1 200ma A	0.340	0.540	1 10	0.930	1.420
1.2 ≤ Vouт < 1.5	- Iоит=300mA	0.290	0.500	Тоит=1А	0.900	1.380
1.5 ≤ Vouт < 2.6		0.230	0.310		0.700	1.100
2.6 ≤ Vouт < 3.3		0.150	0.180		0.500	0.750
3.3 ≤ V _{OUT} ≤ 5.5		0.140	0.170		0.450	0.650

APPLICATION INFORMATION

Typical Application Circuits



Recommendation value of the external capacitors

Vоит	Capacitors		
V _{OUT} ≤ 3.6V	C _{IN}	Kyocera 2.2μF (size:1005)	[CM05X5R225M06AB]
VOUT ≤ 3.0 V	Соит	Kyocera 2.2μF (size:1608)	[CM105X5R225K06AB]
\/> 2 G\/	CIN	Kyocera 2.2μF (size:1608)	[CM105X5R225K06AB]
V _{ОUТ} > 3.6V	Соит	Kyocera 4.7μF (size:1608)	[CM105X5R475M06AB]

Technical Notes on the External Components

When using this IC, consider following points:

Phase Compensation

In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, use a capacitor C_{OUT} with good frequency characteristics and ESR (Equivalent Series Resistance).

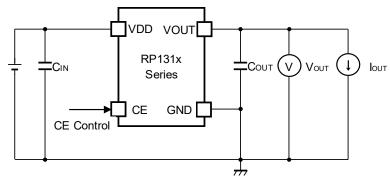
If a tantalum capacitor is used, and its ESR of C_{OUT} is large, the loop oscillation may result. Because of this, select C_{OUT} carefully considering its frequency characteristics.

PCB Layout

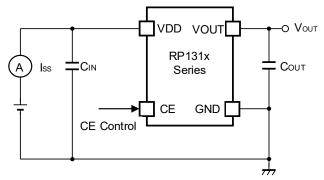
Make V_{DD} and GND lines sufficient. If their impedance is high, noise pickup or unstable operation may result. Connect a capacitor C_{IN} between V_{DD} and GND pin with a capacitance value as "Recommendation value of the external capacitors" above or more, and as close as possible to the pins.

Set external components, especially the output capacitor C_{OUT} , as close as possible to the ICs, and make wiring as short as possible.

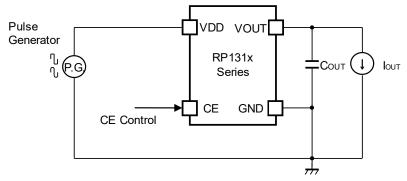
TEST CIRCUITS



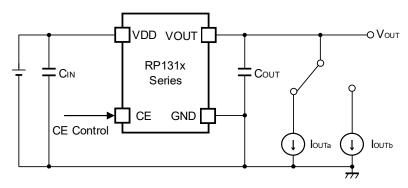
Basic Test Circuit



Test Circuit for Supply Current



Test Circuit for Ripple Rejection

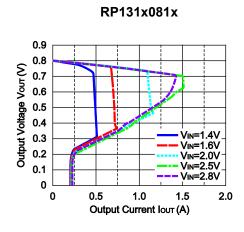


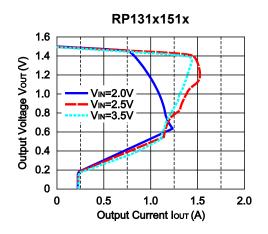
Test Circuit for Load Transient Response

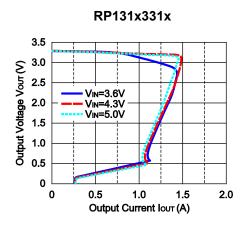
TYPICAL CHARACTERISTICS

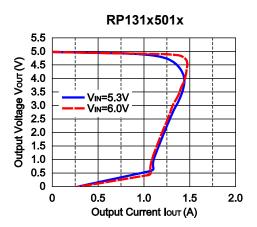
Typical Characteristics are intended to be used as reference data; they are not guaranteed.

1) Output Voltage vs. Output Current ($Ta = 25^{\circ}C$)

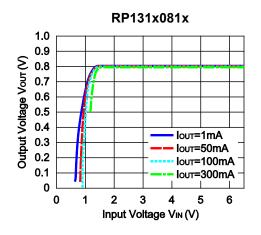


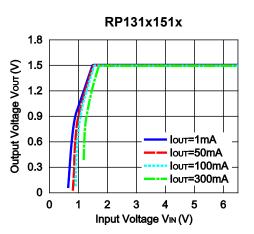


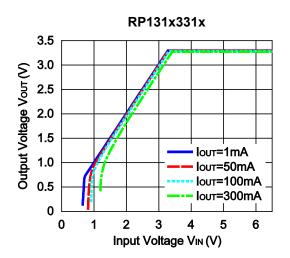


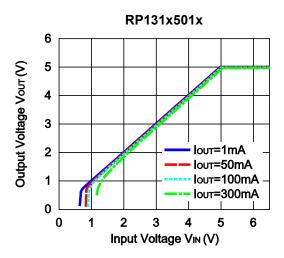


2) Output Voltage vs. Input Voltage (Ta=25°C)

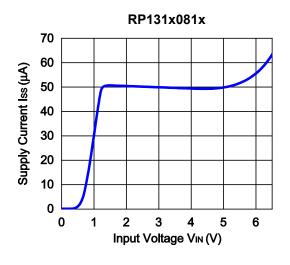


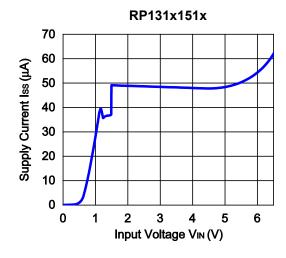


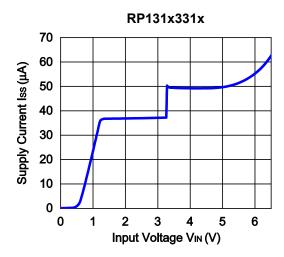


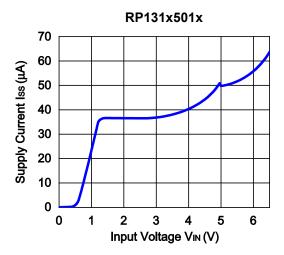


3) Supply Current vs. Input Voltage (Ta=25°C)



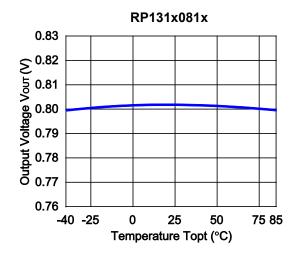


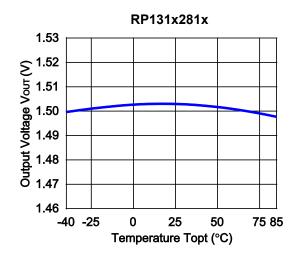


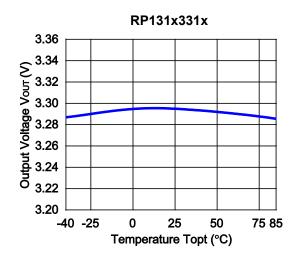


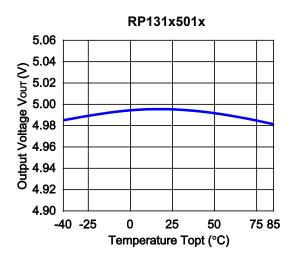
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4) Output Voltage vs. Temperature

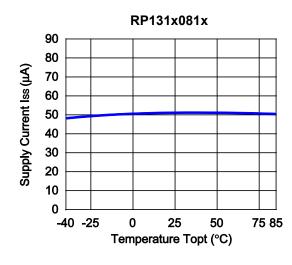


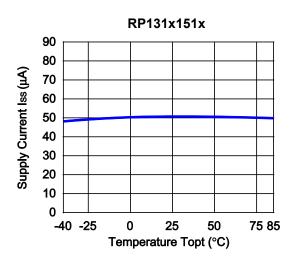




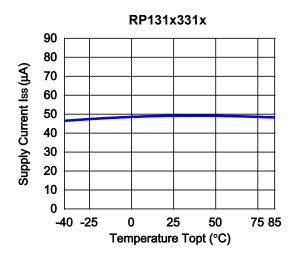


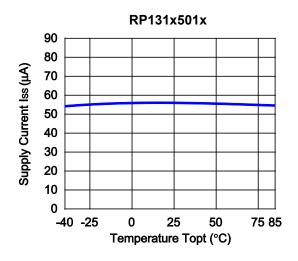
5) Supply Current vs. Temperature



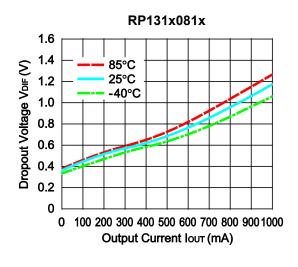


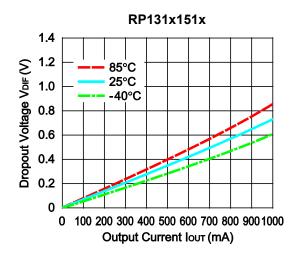
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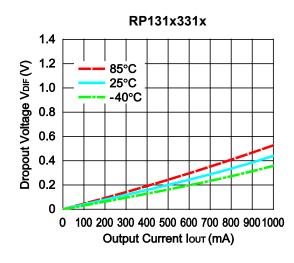


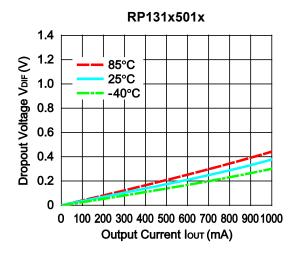


6) Dropout Voltage vs. Output Current

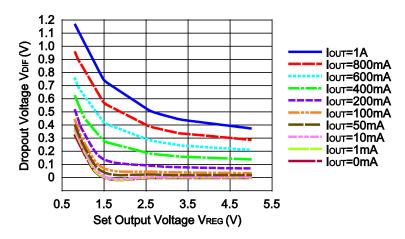




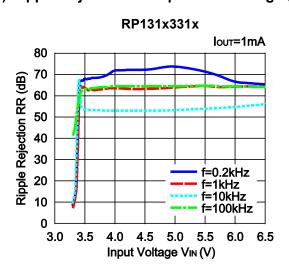


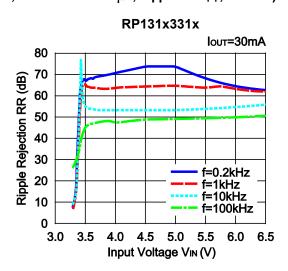


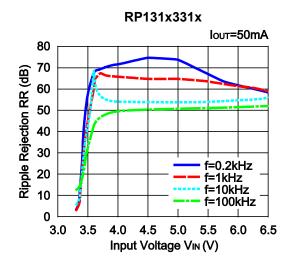
7) Dropout Voltage vs. Set Output Voltage

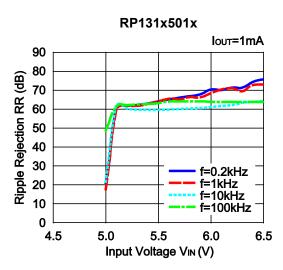


8) Ripple Rejection vs. Input Bias Voltage (C1=none, C2=Ceramic 1.0μF, Ripple=0.2V_{PP}, Ta=25°C)

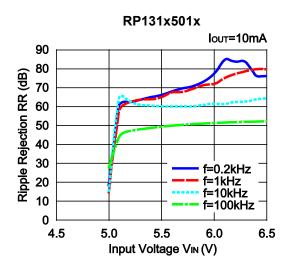


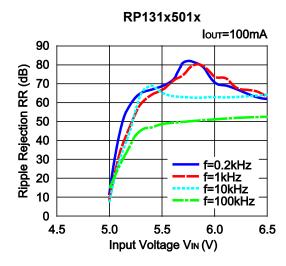




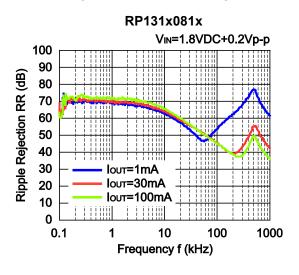


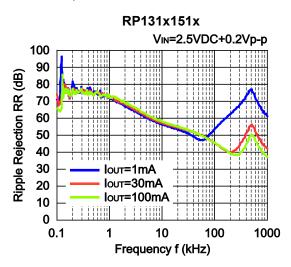
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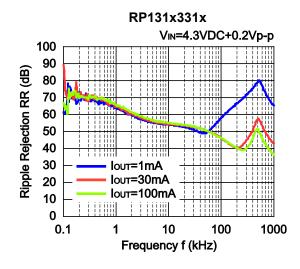


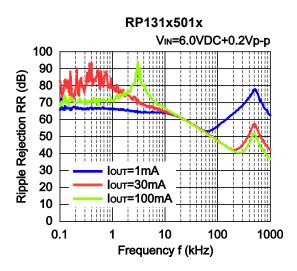


9) Ripple Rejection vs. Frequency (C1=none, C2=Ceramic 4.7μF, Ta=25°C)



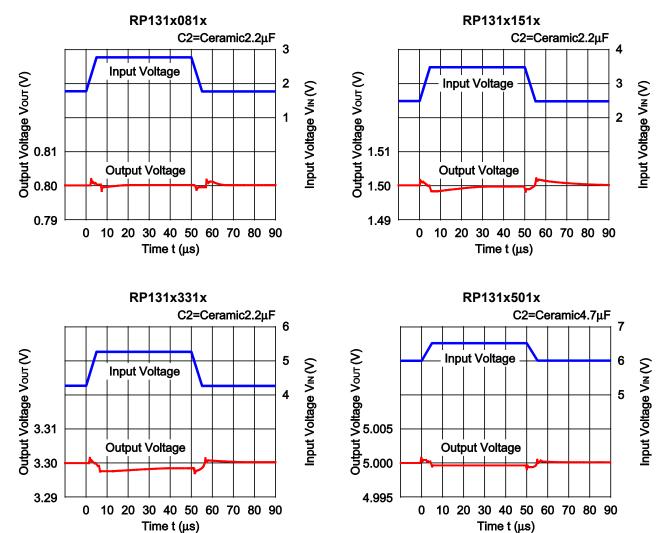




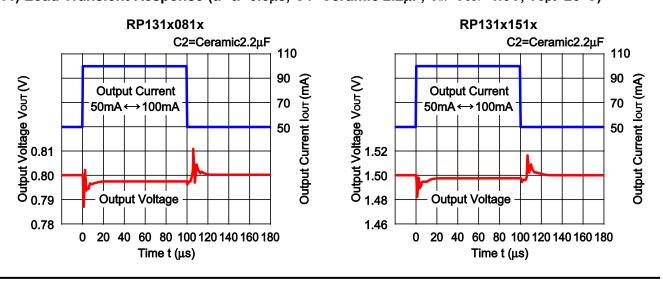


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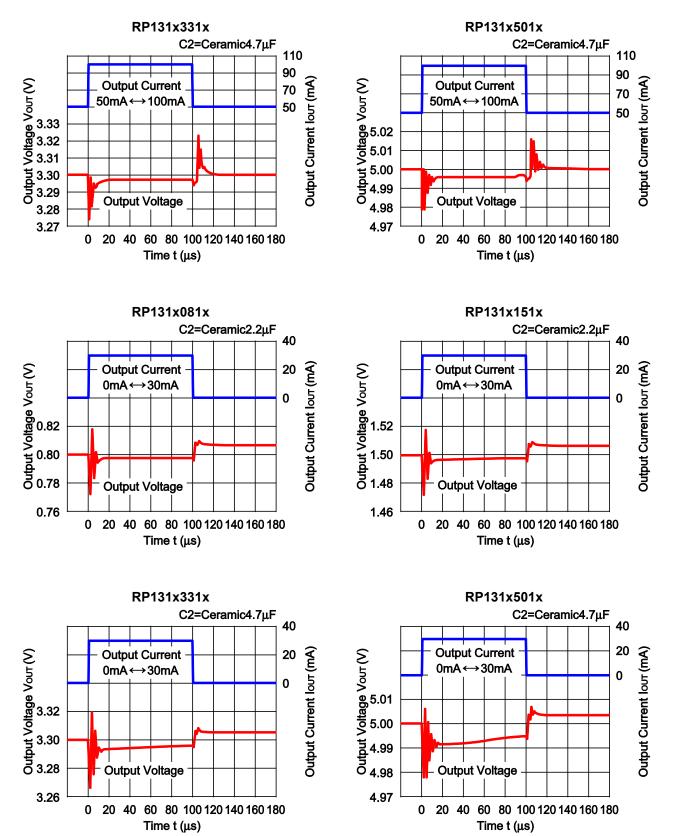
10) Input Transient Response (Ιουτ=100mA, tr=tf=5μs, C1=none, Ta=25°C)



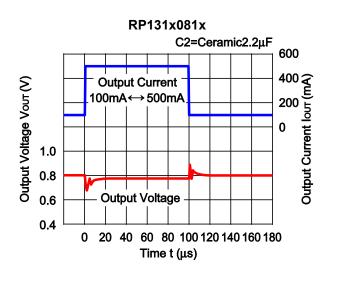
11) Load Transient Response (tr=tf=0.5μs, C1=Ceramic 2.2μF, V_{IN}=V_{OUT}+1.0V, Topt=25°C)

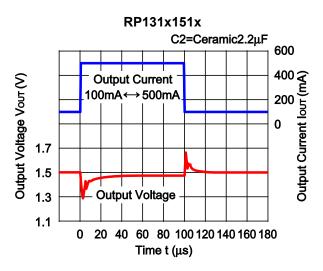


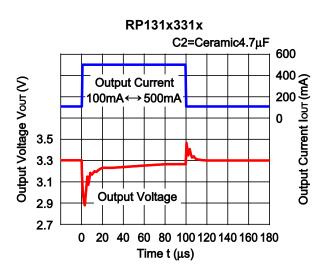
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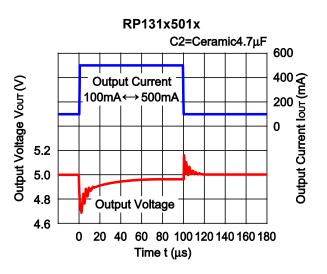


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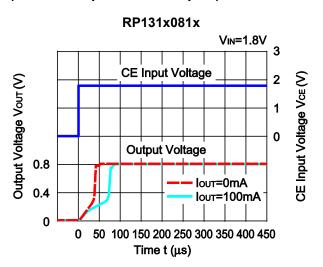


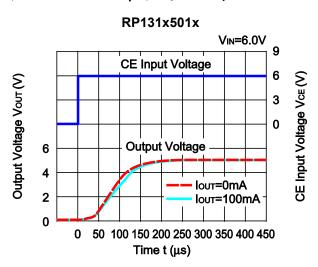




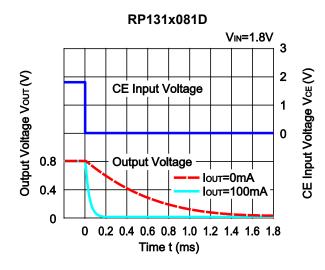


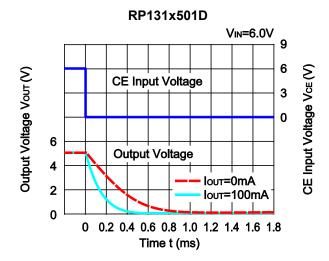
12) Turn On Speed with CE pin (C1=Ceramic 2.2μF, C2=Ceramic 4.7μF, Topt=25°C)



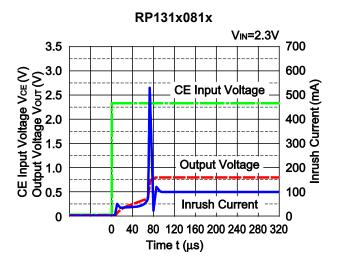


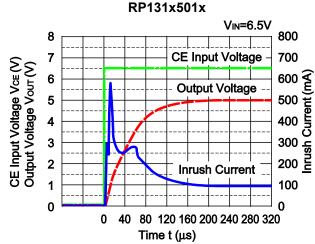
13) Turn Off Speed with CE pin (D Version) (C1=Ceramic 2.2μF, C2=Ceramic 4.7μF, Ta=25°C)



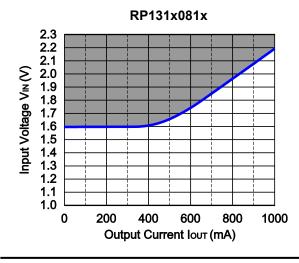


14) Inrush Current at turning on (C1=Ceramic 2.2μF, C2=Ceramic 4.7μF, Topt=25°C)





15) Minimum Operating Voltage



Hatched area is available for 0.8V output.

ESR vs. Output Current

When using these ICs, consider the following points:

The relations between Iout (Output Current) and ESR of an output capacitor are shown below.

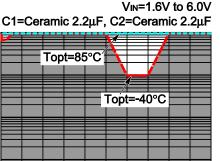
The conditions when the white noise level is under 40μV (Avg.) are marked as the hatched area in the graph.

Measurement conditions

100

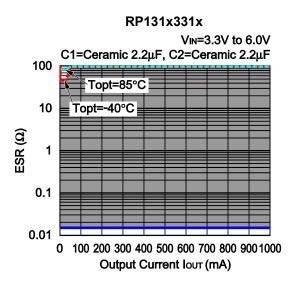
Frequency Band: 10Hz to 3MHz Temperature : -40°C to 85°C

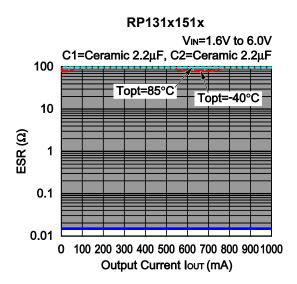
C1 : 2.2μF (Kyocera, CM05X5R225M04AD) C2 : 2.2μF (Kyocera, CM105X5R225K06AE) 4.7μF (Kyocera, CM105X5R475M06AB)

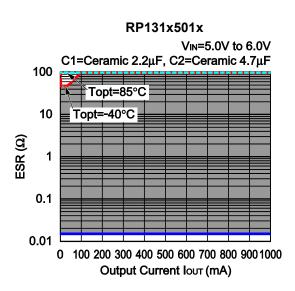


RP131x081x

10 ESR (Ω) 1 0.1 0.01 0 100 200 300 400 500 600 700 800 900 1000 Output Current lout (mA)







PD-DFN1616-6B-(85125150)-JE-B

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51.

Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.2 mm × 25 pcs

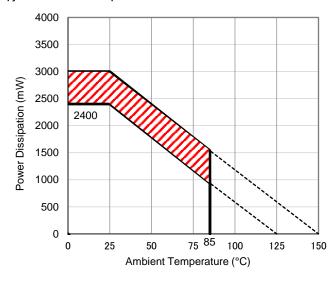
Measurement Result

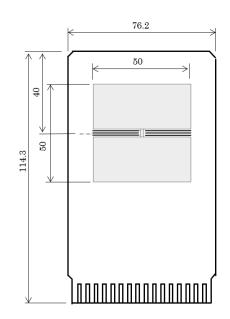
 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$

Item	Measurement Result
Power Dissipation	2400 mW
Thermal Resistance (θja)	θja = 41°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 11°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter



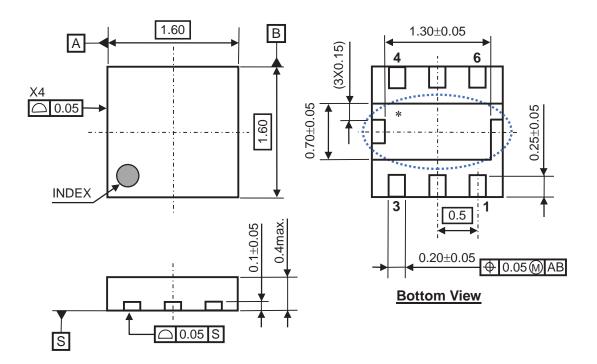


Power Dissipation vs. Ambient Temperature

Measurement Board Pattern

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years



DFN1616-6B Package Dimensions (Unit: mm)

i

^{*} The tab on the bottom of the package shown by blue circle is a substrate potential (GND). It is recommended that this tab be connected to the ground plane pin on the board but it is possible to leave the tab floating.

PD-DFN(PL)1820-6-(85125150)-JE-B

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51.

Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.2 mm × 36 pcs

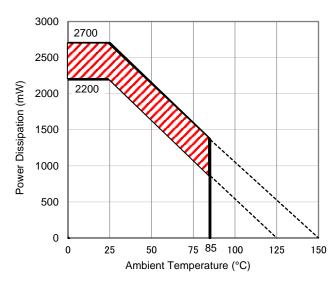
Measurement Result

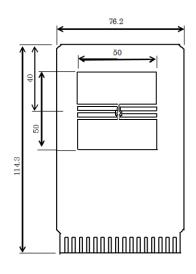
 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$

ltem	Measurement Result
Power Dissipation	2200 mW
Thermal Resistance (θja)	θja = 45°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 18°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter



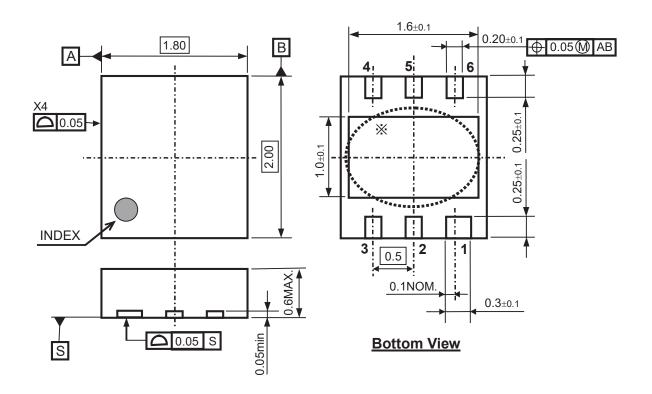


Power Dissipation vs. Ambient Temperature

Measurement Board Pattern

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years



DFN(PL)1820-6 Package Dimensions (Unit: mm)

i

^{*} The tab on the bottom of the package is substrate level (GND). It is recommended that the tab be connected to the ground plane on the board, or otherwise be left floating.

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
	Outer Layer (First Layer): Less than 95% of 50 mm Square
Copper Ratio	Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square
	Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 13 pcs

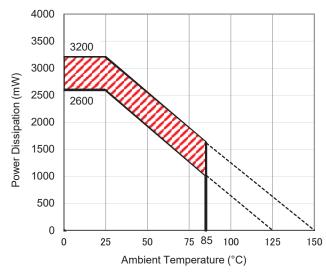
Measurement Result

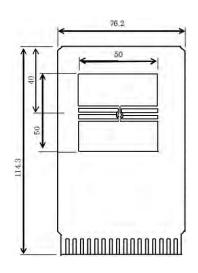
 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$

Item	Measurement Result
Power Dissipation	2600 mW
Thermal Resistance (θja)	θja = 38°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 13°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter





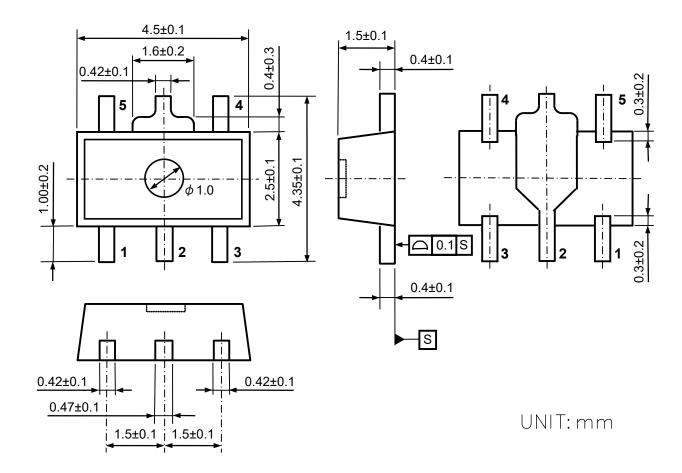
Power Dissipation vs. Ambient Temperature

Measurement Board Pattern

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

I



SOT-89-5 Package Dimensions

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square
	Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square
	Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 28 pcs

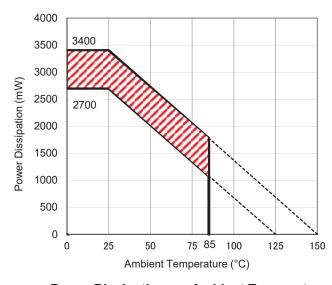
Measurement Result

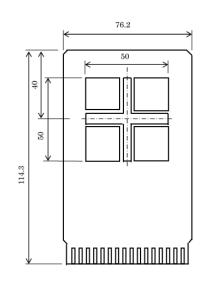
 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$

Item	Measurement Result
Power Dissipation	2700 mW
Thermal Resistance (θja)	θja = 37°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 7°C/W

 θ ja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter





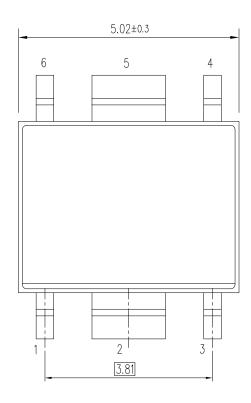
Power Dissipation vs. Ambient Temperature

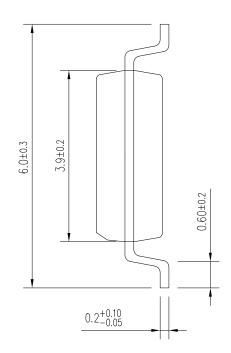
Measurement Board Pattern

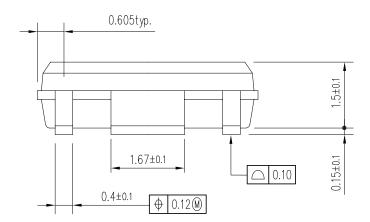
The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

I







UNIT: mm

HSOP-6J Package Dimensions

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 21 pcs

 Measurement Result
 (Ta = 25°C, Tjmax = 125°C)

 Item
 Measurement Result

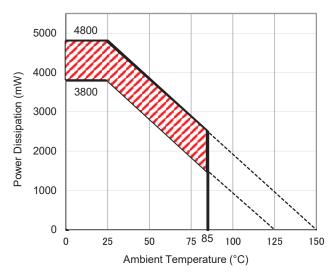
 Power Dissipation
 3800 mW

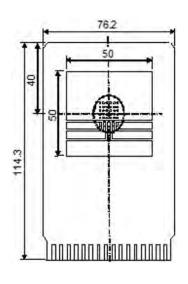
 Thermal Resistance (θja)
 θja = 26°C/W

Thermal Characterization Parameter (ψjt) ψjt = 7°C/W

 θ ja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter





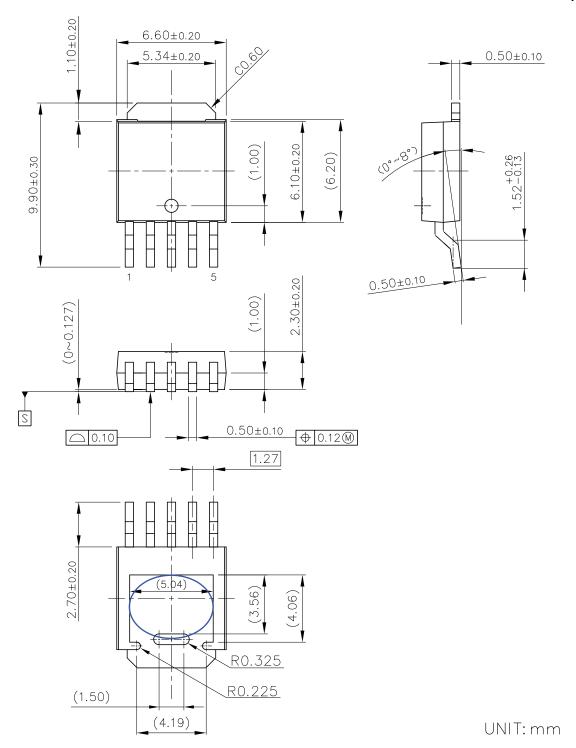
Power Dissipation vs. Ambient Temperature

Measurement Board Pattern

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

i



TO-252-5-P2 Package Dimensions

I

^{*} The tab on the bottom of the package shown by blue circle is a substrate potential (GND). It is recommended that this tab be connected to the ground plane on the board but it is possible to leave the tab floating.

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 - When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.
 - Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
 - 8-3. Remedies after Quality Warranty Period
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